



# DA2JF8100L

Silicon epitaxial planar type

For high speed switching circuits

■ Features

- Small reverse current IR
- High repetitive peak reverse voltage VRRM
- Halogen-free / RoHS compliant  
(EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

■ Marking Symbol: 5A

■ Packaging

Embossed type (Thermo-compression sealing) : 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit
Repetitive peak reverse voltage	VRRM	800	V
Non-repetitive peak peak reverse voltage	VRSM	800	V
Forward current	IF	200	mA
Non-repetitive peak forward surge current <sup>*1,2</sup>	IFSM	1	A
Junction temperature	Tj	-40 to +150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-40 to +150	°C

Note) \*1 Mounted on an alumina PC board

\*2 50 Hz sine wave 1 cycle ( Non-repetitive peak current )

